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### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	S08
Core Size	8-Bit
Speed	40MHz
Connectivity	I <sup>2</sup> C, LINbus, SCI, SPI
Peripherals	LVD, POR, PWM, WDT
Number of I/O	12
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	16-TSSOP (0.173", 4.40mm Width)
Supplier Device Package	16-TSSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/s9s08sg8e2vtg">https://www.e-xfl.com/product-detail/nxp-semiconductors/s9s08sg8e2vtg</a>

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must be programmed to logic 0 to enable block protection. Therefore the value 0xF8 must be programmed into NVPROT to protect addresses 0xFA00 through 0xFFFF.

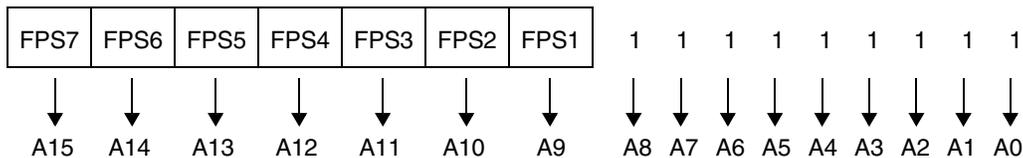


Figure 4-4. Block Protection Mechanism

One use for block protection is to block protect an area of FLASH memory for a bootloader program. This bootloader program then can be used to erase the rest of the FLASH memory and reprogram it. Because the bootloader is protected, it remains intact even if MCU power is lost in the middle of an erase and reprogram operation.

### 4.5.7 Vector Redirection

Whenever any block protection is enabled, the reset and interrupt vectors will be protected. Vector redirection allows users to modify interrupt vector information without unprotecting bootloader and reset vector space. Vector redirection is enabled by programming the FNORED bit in the NVOPT register located at address 0xFFBF to zero. For redirection to occur, at least some portion but not all of the FLASH memory must be block protected by programming the NVPROT register located at address 0xFFBD. All of the interrupt vectors (memory locations 0xFFC0–0xFFFFD) are redirected, though the reset vector (0xFFFE:FFFF) is not.

For example, if 512 bytes of FLASH are protected, the protected address region is from 0xFE00 through 0xFFFF. The interrupt vectors (0xFFC0–0xFFFFD) are redirected to the locations 0xFDC0–0xFDFD. Now, if an SPI interrupt is taken for instance, the values in the locations 0xFDE0:FDE1 are used for the vector instead of the values in the locations 0xFFE0:FFE1. This allows the user to reprogram the unprotected portion of the FLASH with new program code including new interrupt vector values while leaving the protected area, which includes the default vector locations, unchanged.

## 4.6 Security

The MC9S08SG8 includes circuitry to prevent unauthorized access to the contents of FLASH and RAM memory. When security is engaged, FLASH and RAM are considered secure resources. Direct-page registers, high-page registers, and the background debug controller are considered unsecured resources. Programs executing within secure memory have normal access to any MCU memory locations and resources. Attempts to access a secure memory location with a program executing from an unsecured memory space or through the background debug interface are blocked (writes are ignored and reads return all 0s).

Security is engaged or disengaged based on the state of two nonvolatile register bits (SEC01:SEC00) in the FOPT register. During reset, the contents of the nonvolatile location NVOPT are copied from FLASH into the working FOPT register in high-page register space. A user engages security by programming the NVOPT location which can be done at the same time the FLASH memory is programmed. The 1:0 state disengages security and the other three combinations engage security. Notice the erased state (1:1) makes

The status flag corresponding to the interrupt source must be acknowledged (cleared) before returning from the ISR. Typically, the flag is cleared at the beginning of the ISR so that if another interrupt is generated by this same source, it will be registered so it can be serviced after completion of the current ISR.

## 5.5.2 Interrupt Vectors, Sources, and Local Masks

Table 5-2 provides a summary of all interrupt sources. Higher-priority sources are located toward the bottom of the table. The high-order byte of the address for the interrupt service routine is located at the first address in the vector address column, and the low-order byte of the address for the interrupt service routine is located at the next higher address.

When an interrupt condition occurs, an associated flag bit becomes set. If the associated local interrupt enable is 1, an interrupt request is sent to the CPU. Within the CPU, if the global interrupt mask (I bit in the CCR) is 0, the CPU will finish the current instruction; stack the PCL, PCH, X, A, and CCR CPU registers; set the I bit; and then fetch the interrupt vector for the highest priority pending interrupt. Processing then continues in the interrupt service routine.

## Chapter 8

# 5-V Analog Comparator (S08ACMPV2)

### 8.1 Introduction

The analog comparator module (ACMP) provides a circuit for comparing two analog input voltages or for comparing one analog input voltage to an internal reference voltage. The comparator circuit is designed to operate across the full range of the supply voltage (rail-to-rail operation).

Figure 8-1 shows the MC9S08SG8 block diagram with the ACMP module highlighted.

#### 8.1.1 ACMP Configuration Information

When using the bandgap reference voltage for input to ACMP+, the user must enable the bandgap buffer by setting BGBE = 1 in SPMSC1 see [Section 5.7.6, “System Power Management Status and Control 1 Register \(SPMSC1\)”](#). For value of bandgap voltage reference see [Section A.6, “DC Characteristics”](#).

#### 8.1.2 ACMP in Stop3 Mode

S08ACMPV2 continues to operate in stop3 mode if enabled. If ACOPE is enabled, comparator output will operate as in the normal operating mode and will control ACMPO pin. The MCU is brought out of stop when a compare event occurs and ACIE is enabled; ACF flag sets accordingly.

#### 8.1.3 ACMP/TPM Configuration Information

The ACMP module can be configured to connect the output of the analog comparator to TPM1 input capture channel 0 by setting ACIC in SOPT2. With ACIC set, the TPM1CH0 pin is not available externally regardless of the configuration of the TPM1 module for channel 0.

## 8.1.4 Features

The ACMP has the following features:

- Full rail to rail supply operation.
- Selectable interrupt on rising edge, falling edge, or either rising or falling edges of comparator output.
- Option to compare to fixed internal bandgap reference voltage.
- Option to allow comparator output to be visible on a pin, ACMPO.
- Can operate in stop3 mode

## 8.1.5 Modes of Operation

This section defines the ACMP operation in wait, stop and background debug modes.

### 8.1.5.1 ACMP in Wait Mode

The ACMP continues to run in wait mode if enabled before executing the WAIT instruction. Therefore, the ACMP can be used to bring the MCU out of wait mode if the ACMP interrupt, ACIE is enabled. For lowest possible current consumption, the ACMP should be disabled by software if not required as an interrupt source during wait mode.

### 8.1.5.2 ACMP in Stop Modes

#### 8.1.5.2.1 Stop3 Mode Operation

The ACMP continues to operate in Stop3 mode if enabled and compare operation remains active. If ACOPE is enabled, comparator output operates as in the normal operating mode and comparator output is placed onto the external pin. The MCU is brought out of stop when a compare event occurs and ACIE is enabled; ACF flag sets accordingly.

If stop is exited with a reset, the ACMP will be put into its reset state.

#### 8.1.5.2.2 Stop2 and Stop1 Mode Operation

During either Stop2 and Stop1 mode, the ACMP module will be fully powered down. Upon wake-up from Stop2 or Stop1 mode, the ACMP module will be in the reset state.

### 8.1.5.3 ACMP in Active Background Mode

When the microcontroller is in active background mode, the ACMP will continue to operate normally.

## 8.1.6 Block Diagram

The block diagram for the Analog Comparator module is shown [Figure 8-2](#).

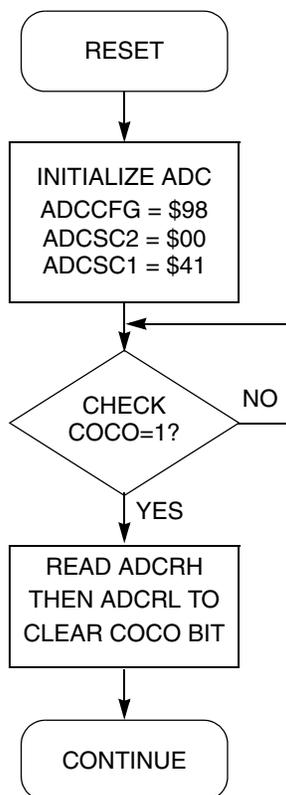


Figure 9-14. Initialization Flowchart for Example

## 9.6 Application Information

This section contains information for using the ADC module in applications. The ADC has been designed to be integrated into a microcontroller for use in embedded control applications requiring an A/D converter.

### 9.6.1 External Pins and Routing

The following sections discuss the external pins associated with the ADC module and how they should be used for best results.

#### 9.6.1.1 Analog Supply Pins

The ADC module has analog power and ground supplies ( $V_{DDAD}$  and  $V_{SSAD}$ ) which are available as separate pins on some devices. On other devices,  $V_{SSAD}$  is shared on the same pin as the MCU digital  $V_{SS}$ , and on others, both  $V_{SSAD}$  and  $V_{DDAD}$  are shared with the MCU digital supply pins. In these cases, there are separate pads for the analog supplies which are bonded to the same pin as the corresponding digital supply so that some degree of isolation between the supplies is maintained.

When available on a separate pin, both  $V_{DDAD}$  and  $V_{SSAD}$  must be connected to the same voltage potential as their corresponding MCU digital supply ( $V_{DD}$  and  $V_{SS}$ ) and must be routed carefully for maximum noise immunity and bypass capacitors placed as near as possible to the package.

### 10.3.3 ICS Trim Register (ICSTRM)

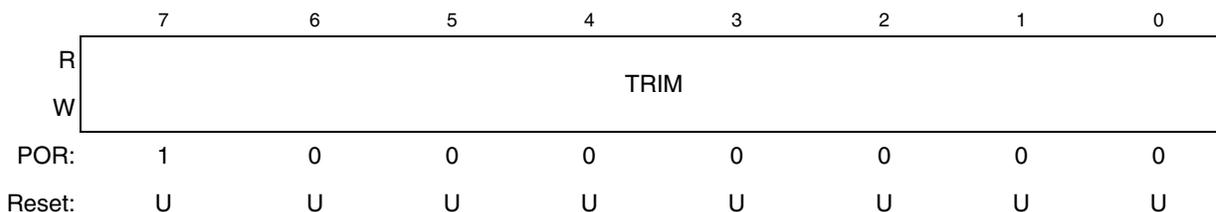


Figure 10-5. ICS Trim Register (ICSTRM)

Table 10-4. ICS Trim Register Field Descriptions

Field	Description
7:0 TRIM	<p><b>ICS Trim Setting</b> — The TRIM bits control the internal reference clock frequency by controlling the internal reference clock period. The bits' effect are binary weighted (i.e., bit 1 will adjust twice as much as bit 0). Increasing the binary value in TRIM will increase the period, and decreasing the value will decrease the period.</p> <p>An additional fine trim bit is available in ICSSC as the FTRIM bit.</p>

### 10.3.4 ICS Status and Control (ICSSC)

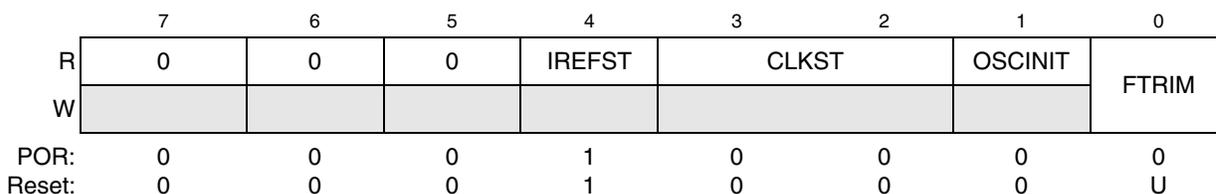


Figure 10-6. ICS Status and Control Register (ICSSC)

Table 10-5. ICS Status and Control Register Field Descriptions

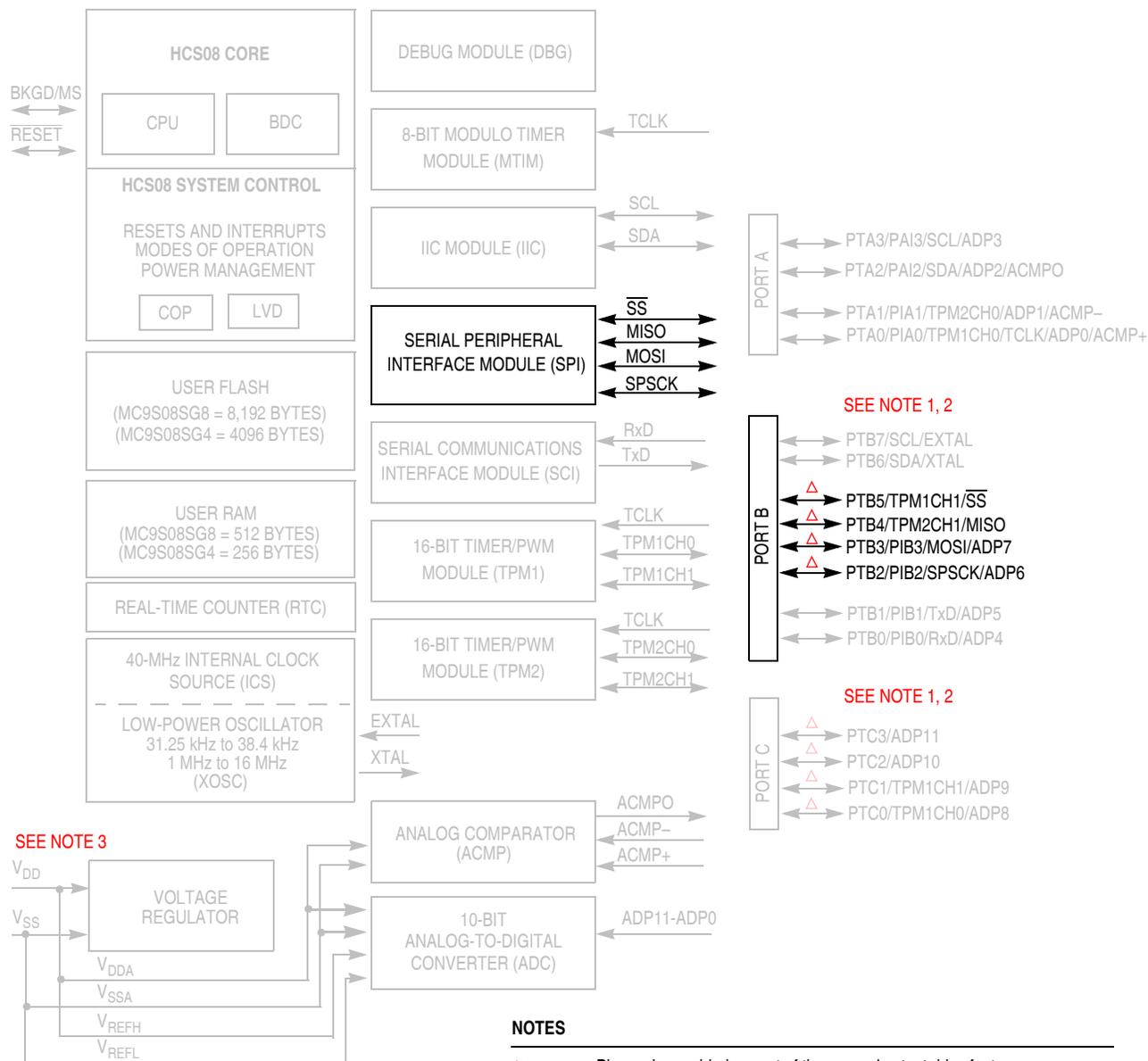
Field	Description
7:5	Reserved, should be cleared.
4 IREFST	<p><b>Internal Reference Status</b> — The IREFST bit indicates the current source for the reference clock. The IREFST bit does not update immediately after a write to the IREFS bit due to internal synchronization between clock domains.</p> <p>0 Source of reference clock is external clock. 1 Source of reference clock is internal clock.</p>
3-2 CLKST	<p><b>Clock Mode Status</b> — The CLKST bits indicate the current clock mode. The CLKST bits don't update immediately after a write to the CLKST bits due to internal synchronization between clock domains.</p> <p>00 Output of FLL is selected. 01 FLL Bypassed, Internal reference clock is selected. 10 FLL Bypassed, External reference clock is selected. 11 Reserved.</p>

If EREFSTEN is set and the ERCLKEN bit is written to 1, the external reference clock will keep running during stop mode in order to provide a fast recovery upon exiting stop.

### 10.4.7 Fixed Frequency Clock

The ICS presents the divided FLL reference clock as ICSFFCLK for use as an additional clock source for peripheral modules. The ICS provides an output signal (ICSFFE) which indicates when the ICS is providing ICSOUT frequencies four times or greater than the divided FLL reference clock (ICSFFCLK). In FLL Engaged mode (FEI and FEE) this is always true and ICSFFE is always high. In ICS Bypass modes, ICSFFE will get asserted for the following combinations of BDIV and RDIV values:

- BDIV=00 (divide by 1), RDIV  $\geq$  010
- BDIV=01 (divide by 2), RDIV  $\geq$  011
- BDIV=10 (divide by 4), RDIV  $\geq$  100
- BDIV=11 (divide by 8), RDIV  $\geq$  101



**NOTES**

- △ = Pin can be enabled as part of the ganged output drive feature.
- NOTE 1: Port B not available on 8-pin packages
- NOTE 2: Port C not available on 8-pin or 16-pin packages.
- NOTE 3:  $V_{DDA}/V_{REFH}$  and  $V_{SSA}/V_{REFL}$  are double bonded to  $V_{DD}$  and  $V_{SS}$  respectively.

**Figure 15-1. MC9S08SG8 Block Diagram with SPI Module Highlighted**

## 15.5.2 SPI Interrupts

There are three flag bits, two interrupt mask bits, and one interrupt vector associated with the SPI system. The SPI interrupt enable mask (SPIE) enables interrupts from the SPI receiver full flag (SPRF) and mode fault flag (MODF). The SPI transmit interrupt enable mask (SPTIE) enables interrupts from the SPI transmit buffer empty flag (SPTEF). When one of the flag bits is set, and the associated interrupt mask bit is set, a hardware interrupt request is sent to the CPU. If the interrupt mask bits are cleared, software can poll the associated flag bits instead of using interrupts. The SPI interrupt service routine (ISR) should check the flag bits to determine what event caused the interrupt. The service routine should also clear the flag bit(s) before returning from the ISR (usually near the beginning of the ISR).

## 15.5.3 Mode Fault Detection

A mode fault occurs and the mode fault flag (MODF) becomes set when a master SPI device detects an error on the  $\overline{SS}$  pin (provided the  $\overline{SS}$  pin is configured as the mode fault input signal). The  $\overline{SS}$  pin is configured to be the mode fault input signal when MSTR = 1, mode fault enable is set (MODFEN = 1), and slave select output enable is clear (SSOE = 0).

The mode fault detection feature can be used in a system where more than one SPI device might become a master at the same time. The error is detected when a master's  $\overline{SS}$  pin is low, indicating that some other SPI device is trying to address this master as if it were a slave. This could indicate a harmful output driver conflict, so the mode fault logic is designed to disable all SPI output drivers when such an error is detected.

When a mode fault is detected, MODF is set and MSTR is cleared to change the SPI configuration back to slave mode. The output drivers on the SPSCK, MOSI, and MISO (if not bidirectional mode) are disabled.

MODF is cleared by reading it while it is set, then writing to the SPI control register 1 (SPIC1). User software should verify the error condition has been corrected before changing the SPI back to master mode.

# Chapter 16

## Timer Pulse-Width Modulator (S08TPMV3)

### 16.1 Introduction

The TPM uses one input/output (I/O) pin per channel, TPMxCHn where x is the TPM number (for example, 1 or 2) and n is the channel number (for example, 0–1). The TPM shares its I/O pins with general-purpose I/O port pins (refer to the [Pins and Connections](#) chapter for more information).

All MC9S08SG8 MCUs have two TPM modules. The number of channels available depends on the pin quantity of the package, as shown in [Table 16-1](#):

**Table 16-1. MC9S08SG8 Features by MCU and Package**

Feature	MC9S08SG8/4		
	20	16	8
Pin quantity	20	16	8
TPM1 channels	2	2	1 <sup>1</sup>
TPM2 channels	2	2	1 <sup>1</sup>

<sup>1</sup> The 8-pin device does not have TPM1CH1 or TPM2CH1 bonded out, but those timer channels are available to the user to use as software compares.

[Figure 16-1](#) shows the MC9S08SG8 block diagram with the TPM modules highlighted.

#### 16.1.1 ACMP/TPM Configuration Information

The ACMP module can be configured to connect the output of the analog comparator to TPM1 input capture channel 0 by setting ACIC in SOPT2. With ACIC set, the TPM1CH0 pin is not available externally regardless of the configuration of the TPM1 module for channel 0.

#### 16.1.2 TPM Configuration Information

The external clock for the TPM modules, TPMCLK, is selected by setting CLKS[B:A] = 1:1 in TPMxSC, which selects the TCLK pin input. The TCLK input on PTA5 can be enabled as external clock inputs to both TPM modules and MTIM simultaneously.

the TPM counter is a free-running counter then the update is made when the TPM counter changes from 0xFFFFE to 0xFFFF.

#### 16.4.2.4 Center-Aligned PWM Mode

This type of PWM output uses the up/down counting mode of the timer counter (CPWMS=1). The output compare value in TPMxCnVH:TPMxCnVL determines the pulse width (duty cycle) of the PWM signal while the period is determined by the value in TPMxMODH:TPMxMODL. TPMxMODH:TPMxMODL should be kept in the range of 0x0001 to 0x7FFF because values outside this range can produce ambiguous results. ELSnA will determine the polarity of the CPWM output.

$$\text{pulse width} = 2 \times (\text{TPMxCnVH:TPMxCnVL})$$

$$\text{period} = 2 \times (\text{TPMxMODH:TPMxMODL}); \text{TPMxMODH:TPMxMODL}=0\text{x}0001\text{-}0\text{x}7\text{FFF}$$

If the channel-value register TPMxCnVH:TPMxCnVL is zero or negative (bit 15 set), the duty cycle will be 0%. If TPMxCnVH:TPMxCnVL is a positive value (bit 15 clear) and is greater than the (non-zero) modulus setting, the duty cycle will be 100% because the duty cycle compare will never occur. This implies the usable range of periods set by the modulus register is 0x0001 through 0x7FFE (0x7FFF if you do not need to generate 100% duty cycle). This is not a significant limitation. The resulting period would be much longer than required for normal applications.

TPMxMODH:TPMxMODL=0x0000 is a special case that should not be used with center-aligned PWM mode. When CPWMS=0, this case corresponds to the counter running free from 0x0000 through 0xFFFF, but when CPWMS=1 the counter needs a valid match to the modulus register somewhere other than at 0x0000 in order to change directions from up-counting to down-counting.

The output compare value in the TPM channel registers (times 2) determines the pulse width (duty cycle) of the CPWM signal (Figure 16-16). If ELSnA=0, a compare occurred while counting up forces the CPWM output signal low and a compare occurred while counting down forces the output high. The counter counts up until it reaches the modulo setting in TPMxMODH:TPMxMODL, then counts down until it reaches zero. This sets the period equal to two times TPMxMODH:TPMxMODL.

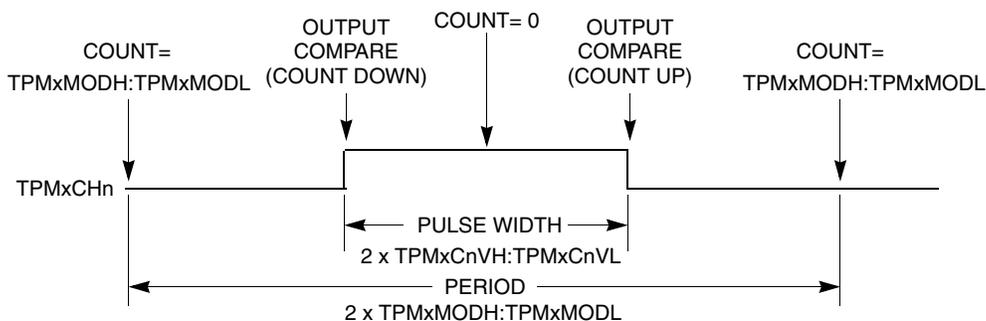
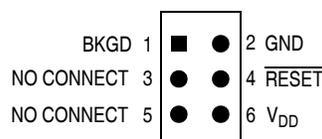


Figure 16-16. CPWM Period and Pulse Width (ELSnA=0)

Center-aligned PWM outputs typically produce less noise than edge-aligned PWMs because fewer I/O pin transitions are lined up at the same system clock edge. This type of PWM is also required for some types of motor drives.

- Non-intrusive commands can be executed at any time even while the user’s program is running. Non-intrusive commands allow a user to read or write MCU memory locations or access status and control registers within the background debug controller.

Typically, a relatively simple interface pod is used to translate commands from a host computer into commands for the custom serial interface to the single-wire background debug system. Depending on the development tool vendor, this interface pod may use a standard RS-232 serial port, a parallel printer port, or some other type of communications such as a universal serial bus (USB) to communicate between the host PC and the pod. The pod typically connects to the target system with ground, the BKGD pin,  $\overline{\text{RESET}}$ , and sometimes  $V_{\text{DD}}$ . An open-drain connection to reset allows the host to force a target system reset, which is useful to regain control of a lost target system or to control startup of a target system before the on-chip nonvolatile memory has been programmed. Sometimes  $V_{\text{DD}}$  can be used to allow the pod to use power from the target system to avoid the need for a separate power supply. However, if the pod is powered separately, it can be connected to a running target system without forcing a target system reset or otherwise disturbing the running application program.



**Figure 17-1. BDM Tool Connector**

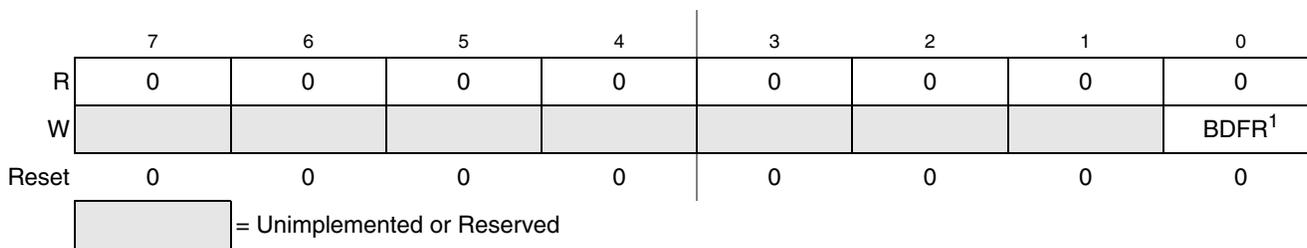
## 17.2.1 BKGD Pin Description

BKGD is the single-wire background debug interface pin. The primary function of this pin is for bidirectional serial communication of active background mode commands and data. During reset, this pin is used to select between starting in active background mode or starting the user’s application program. This pin is also used to request a timed sync response pulse to allow a host development tool to determine the correct clock frequency for background debug serial communications.

BDC serial communications use a custom serial protocol first introduced on the M68HC12 Family of microcontrollers. This protocol assumes the host knows the communication clock rate that is determined by the target BDC clock rate. All communication is initiated and controlled by the host that drives a high-to-low edge to signal the beginning of each bit time. Commands and data are sent most significant bit first (MSB first). For a detailed description of the communications protocol, refer to [Section 17.2.2, “Communication Details.”](#)

If a host is attempting to communicate with a target MCU that has an unknown BDC clock rate, a SYNC command may be sent to the target MCU to request a timed sync response signal from which the host can determine the correct communication speed.

BKGD is a pseudo-open-drain pin and there is an on-chip pullup so no external pullup resistor is required. Unlike typical open-drain pins, the external RC time constant on this pin, which is influenced by external capacitance, plays almost no role in signal rise time. The custom protocol provides for brief, actively driven speedup pulses to force rapid rise times on this pin without risking harmful drive level conflicts. Refer to [Section 17.2.2, “Communication Details,”](#) for more detail.



<sup>1</sup> BDFR is writable only through serial background mode debug commands, not from user programs.

**Figure 17-6. System Background Debug Force Reset Register (SBDFR)**

**Table 17-3. SBDFR Register Field Description**

Field	Description
0 BDFR	<b>Background Debug Force Reset</b> — A serial active background mode command such as WRITE_BYTE allows an external debug host to force a target system reset. Writing 1 to this bit forces an MCU reset. This bit cannot be written from a user program.

### 17.4.3 DBG Registers and Control Bits

The debug module includes nine bytes of register space for three 16-bit registers and three 8-bit control and status registers. These registers are located in the high register space of the normal memory map so they are accessible to normal application programs. These registers are rarely if ever accessed by normal user application programs with the possible exception of a ROM patching mechanism that uses the breakpoint logic.

#### 17.4.3.1 Debug Comparator A High Register (DBGCAH)

This register contains compare value bits for the high-order eight bits of comparator A. This register is forced to 0x00 at reset and can be read at any time or written at any time unless ARM = 1.

#### 17.4.3.2 Debug Comparator A Low Register (DBGCAL)

This register contains compare value bits for the low-order eight bits of comparator A. This register is forced to 0x00 at reset and can be read at any time or written at any time unless ARM = 1.

#### 17.4.3.3 Debug Comparator B High Register (DBGCBH)

This register contains compare value bits for the high-order eight bits of comparator B. This register is forced to 0x00 at reset and can be read at any time or written at any time unless ARM = 1.

#### 17.4.3.4 Debug Comparator B Low Register (DBGCBL)

This register contains compare value bits for the low-order eight bits of comparator B. This register is forced to 0x00 at reset and can be read at any time or written at any time unless ARM = 1.

## A.4 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take  $P_{I/O}$  into account in power calculations, determine the difference between actual pin voltage and  $V_{SS}$  or  $V_{DD}$  and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and  $V_{SS}$  or  $V_{DD}$  will be very small.

**Table A-3. Thermal Characteristics**

Num	C	Rating	Symbol	Value	Unit	Temp Rated <sup>1</sup>			
						Standard	AEC Grade 0		
1	—	Operating temperature range (packaged)	$T_A$	$T_L$ to $T_H$	°C				
				C		–40 to 85	x		
				V		–40 to 105	x		
				M		–40 to 125	x		
				W		–40 to 150		x	
2	D	Maximum junction temperature	$T_J$		°C				
				C		95	x		
				V		115	x		
				M		135	x		
				W		155		x	
3	D	Thermal resistance <sup>2,3</sup> Single-layer board	$\theta_{JA}$	Airflow at 200 ft/min	°C/W				
				Natural Convection					
				8-pin NB SOIC		131	153	x	
				16-pin TSSOP		115	135	x	x
20-pin TSSOP	95	115	x						
4	D	Thermal resistance <sup>2,3</sup> Four-layer board	$\theta_{JA}$	Airflow at 200 ft/min	°C/W				
				Natural Convection					
				8-pin NB SOIC		95	102	x	
				16-pin TSSOP		86	94	x	x
20-pin TSSOP	69	76	x						

<sup>1</sup> Electrical characteristics only apply to the temperature rated devices marked with x.

<sup>2</sup> Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.

<sup>3</sup> Junction to Ambient Natural Convection

## A.5 ESD Protection and Latch-Up Immunity

Although damage from electrostatic discharge (ESD) is much less common on these devices than on early CMOS circuits, normal handling precautions should be used to avoid exposure to static discharge. Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

All ESD testing is in conformity with AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits. During the device qualification ESD stresses were performed for the human body model (HBM) and the charge device model (CDM).

A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

**Table A-4. ESD and Latch-up Test Conditions**

Model	Description	Symbol	Value	Unit
Human Body	Series resistance	R1	1500	$\Omega$
	Storage capacitance	C	100	pF
	Number of pulses per pin	—	3	
Latch-up	Minimum input voltage limit		-2.5	V
	Maximum input voltage limit		7.5	V

**Table A-5. ESD and Latch-Up Protection Characteristics**

No.	Rating <sup>1</sup>	Symbol	Min	Max	Unit
1	Human body model (HBM)	$V_{\text{HBM}}$	$\pm 2000$	—	V
2	Charge device model (CDM)	$V_{\text{CDM}}$	$\pm 500$	—	V
3	Latch-up current at $T_A = 125^\circ\text{C}$	$I_{\text{LAT}}$	$\pm 100$	—	mA

<sup>1</sup> Parameter is achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted.

## A.6 DC Characteristics

This section includes information about power supply requirements and I/O pin characteristics.

**Table A-6. DC Characteristics**

Num	C	Characteristic	Symbol	Condition	Min	Typ <sup>1</sup>	Max	Unit	Temp Rated <sup>2</sup>		
									Stand ard	AEC Grade 0	
1	—	Operating voltage	$V_{DD}$	—	2.7	—	5.5	V	x	x	
2	C	Output high voltage	$V_{OH}$	All I/O pins, low-drive strength	5 V, $I_{Load} = -4$ mA	$V_{DD} - 1.5$	—	—	V	x	x
	P				5 V, $I_{Load} = -2$ mA	$V_{DD} - 0.8$	—	—		x	x
	C	All I/O pins, high-drive strength	3 V, $I_{Load} = -1$ mA	$V_{DD} - 0.8$	—	—	x	x			
	C		5 V, $I_{Load} = -20$ mA	$V_{DD} - 1.5$	—	—	x	x			
	P		5 V, $I_{Load} = -10$ mA	$V_{DD} - 0.8$	—	—	x	x			
	C		3 V, $I_{Load} = -5$ mA	$V_{DD} - 0.8$	—	—	x	x			
3	C	Output high current	$I_{OHT}$	Max total $I_{OH}$ for all ports	$V_{OUT} < V_{DD}$	0	—	-100 -50	mA	x x	
4	C	Output low voltage	$V_{OL}$	All I/O pins low-drive strength	5 V, $I_{Load} = 4$ mA	—	—	1.5	V	x	x
	P				5 V, $I_{Load} = 2$ mA	—	—	0.8		x	x
	C	All I/O pins high-drive strength	3 V, $I_{Load} = 1$ mA	—	—	0.8	x	x			
	C		5 V, $I_{Load} = 20$ mA	—	—	1.5	x	x			
	P		5 V, $I_{Load} = 10$ mA	—	—	0.8	x	x			
	C		3 V, $I_{Load} = 5$ mA	—	—	0.8	x	x			
5	C	Output low current	$I_{OLT}$	Max total $I_{OL}$ for all ports	$V_{OUT} > V_{SS}$	0	—	100 50	mA	x x	
6	P	Input high voltage; all digital inputs	$V_{IH}$		5V	$0.65 \times V_{DD}$	—	—	V	x	x
	C				3V	$0.7 \times V_{DD}$	—	—		x	x
7	P	Input low voltage; all digital inputs	$V_{IL}$		5V	—	—	$0.35 \times V_{DD}$	V	x	x
	C				3V	—	—	$0.35 \times V_{DD}$		x	x
8	C	Input hysteresis	$V_{hys}$		$0.06 \times V_{DD}$				V	x x	
9	P	Input leakage current (per pin)	$ I_{in} $		$V_{in} = V_{DD}$ or $V_{SS}$ temperature > 125 °C	—	0.1 —	1 2	$\mu A$	x x	
10	P	Hi-Z (off-state) leakage current (per pin) input/output port pins	$ I_{oz} $		$V_{in} = V_{DD}$ or $V_{SS}$ ,	—	0.1	1	$\mu A$	x	
		PTB6/SDA/XTAL, $\overline{RESET}$			$V_{in} = V_{DD}$ or $V_{SS}$	—	0.2	2	$\mu A$	x	
		input/output port pins			$V_{in} = V_{DD}$ or $V_{SS}$ temperature > 125 °C	—	0.2	2	$\mu A$	x	

Table A-6. DC Characteristics (continued)

Num	C	Characteristic	Symbol	Condition	Min	Typ <sup>1</sup>	Max	Unit	Temp Rated <sup>2</sup>	
									Stand ard	AEC Grade 0
23	T	Low-voltage inhibit reset/recover hysteresis	$V_{hys}$	5 V	—	100	—	mV	x	x
				3 V	—	60	—		x	x
24	P	Bandgap Voltage Reference <sup>13</sup>	$V_{BG}$		1.18	1.20	1.21	V	x	
					1.17	1.20	1.22	V		x

<sup>1</sup> Typical values are measured at 25°C. Characterized, not tested.

<sup>2</sup> Electrical characteristics only apply to the temperature rated devices marked with x.

<sup>3</sup> When a pin interrupt is configured to detect rising edges, pulldown resistors are used in place of pullup resistors.

<sup>4</sup> The specified resistor value is the actual value internal to the device. The pullup value may measure higher when measured externally on the pin.

<sup>5</sup> Power supply must maintain regulation within operating  $V_{DD}$  range during instantaneous and operating maximum current conditions. If positive injection current ( $V_{In} > V_{DD}$ ) is greater than  $I_{DD}$ , the injection current may flow out of  $V_{DD}$  and could result in external power supply going out of regulation. Ensure external  $V_{DD}$  load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if clock rate is very low (which would reduce overall power consumption).

<sup>6</sup> All functional non-supply pins are internally clamped to  $V_{SS}$  and  $V_{DD}$ .

<sup>7</sup> Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

<sup>8</sup> The  $\overline{RESET}$  pin does not have a clamp diode to  $V_{DD}$ . Do not drive this pin above  $V_{DD}$ .

<sup>9</sup> Maximum is highest voltage that POR will occur.

<sup>10</sup> Simulated, not tested

<sup>11</sup> Device functionality is guaranteed between the LVD threshold VLVD0 and VDD Min. When VDD is below the minimum operating voltage (VDD Min), the analog parameters for the IO pins, ACMP and ADC, are not guaranteed to meet data sheet performance parameters.

<sup>12</sup> In addition to LVD, it is recommended to also use the LVW feature. LVW can trigger an interrupt and be used as an indicator to warn that the VDD is dropping, so that the software can take actions accordingly before the VDD drops below VDD Min

<sup>13</sup> Factory trimmed at  $V_{DD} = 5.0$  V

## A.9 Internal Clock Source (ICS) Characteristics

Table A-9. ICS Frequency Specifications (Temperature Range = -40 to 125°C Ambient)

Num	C	Rating	Symbol	Min	Typ	Max	Unit	Temp Rated <sup>1</sup>	
								Standard	AEC Grade 0
1	P	Internal reference frequency - factory trimmed at $V_{DD} = 5\text{ V}$	$f_{int\_ft}$	—	31.25	—	kHz	x	x
2	P	Internal reference frequency - untrimmed <sup>2</sup>	$f_{int\_ut}$	25	36	41.66	kHz	x	x
3	P	Internal reference frequency - user trimmed	$f_{int\_t}$	31.25	—	39.0625	kHz	x	x
4	D	Internal reference startup time	$t_{irefst}$	—	55	100	$\mu\text{s}$	x	x
5	—	DCO output frequency range - untrimmed <sup>1</sup> value provided for reference: $f_{dco\_ut} = 1024 \times f_{int\_ut}$	$f_{dco\_ut}$	25.6	36.86	42.66	MHz	x	x
6	D	DCO output frequency range - trimmed	$f_{dco\_t}$	32	—	40	MHz	x	
				32	—	36	MHz		x
7	D	Resolution of trimmed DCO output frequency at fixed voltage and temperature (using FTRIM)	$\Delta f_{dco\_res\_t}$	—	$\pm 0.1$	$\pm 0.2$	$\%f_{dco}$	x	x
8	D	Resolution of trimmed DCO output frequency at fixed voltage and temperature (not using FTRIM)	$\Delta f_{dco\_res\_t}$	—	$\pm 0.2$	$\pm 0.4$	$\%f_{dco}$	x	x
9	P	Total deviation from actual trimmed DCO output frequency over voltage and temperature	$\Delta f_{dco\_t}$	—	+ 0.5 - 1.0	$\pm 1.5$	$\%f_{dco}$	x	
				—	+ 0.5 - 1.0	$\pm 3$	$\%f_{dco}$		x
10	D	Total deviation of trimmed DCO output frequency over fixed voltage and temperature range of 0°C to 70 °C	$\Delta f_{dco\_t}$	—	$\pm 0.5$	$\pm 1$	$\%f_{dco}$	x	x
11	D	FLL acquisition time <sup>3</sup>	$t_{acquire}$			1	ms	x	x
12	D	DCO output clock long term jitter (over 2mS interval) <sup>4</sup>	$C_{jitter}$	—	0.02	0.2	$\%f_{dco}$	x	x

<sup>1</sup> Electrical characteristics only apply to the temperature rated devices marked with x.

<sup>2</sup> TRIM register at default value (0x80) and FTRIM control bit at default value (0x0).

<sup>3</sup> This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

<sup>4</sup> Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum  $f_{BUS}$ . Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via  $V_{DD}$  and  $V_{SS}$  and variation in crystal oscillator frequency increase the  $C_{jitter}$  percentage for a given interval.

## A.10 Analog Comparator (ACMP) Electricals

Table A-10. Analog Comparator Electrical Specifications

Num	C	Rating	Symbol	Min	Typ	Max	Unit	Temp Rated <sup>1</sup>	
								Standard	AEC Grade 0
1	—	Supply voltage	$V_{DD}$	2.7	—	5.5	V	x	x
2	D	Supply current (active)	$I_{DDAC}$	—	20	35	$\mu\text{A}$	x	x
3	D	Analog input voltage	$V_{AIN}$	$V_{SS} - 0.3$	—	$V_{DD}$	V	x	x
4	D	Analog input offset voltage	$V_{AIO}$		20	40	mV	x	x
5	D	Analog Comparator hysteresis	$V_H$	3.0	6.0	20.0	mV	x	x
6	D	Analog input leakage current	$I_{ALKG}$	—	—	1.0	$\mu\text{A}$	x	x
7	D	Analog Comparator initialization delay	$t_{AINIT}$	—	—	1.0	$\mu\text{s}$	x	x

<sup>1</sup> Electrical characteristics only apply to the temperature rated devices marked with x.